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## Molecular Crystals and Liquid Crystals

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### Highly Conducting Transition Metal Complexes Derived from the DMIT-Ligand

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## HIGHLY CONDUCTING TRANSITION METAL COMPLEXES DERIVED FROM THE DMIT-LIGAND

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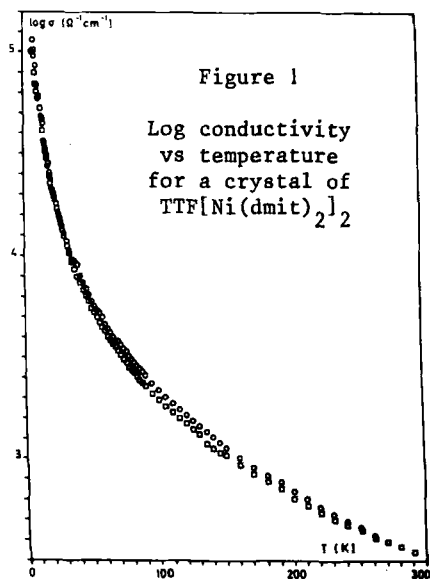
Abstract The nature of the metal M (M = Ni, Pd, Pt) plays a  
predominant role in determining the transport properties and  
the structure of the  $\text{TTF}[\text{M}(\text{dmit})_2]_x$  series.

### INTRODUCTION

It has been well established that, in order to maintain the  
metallic state for a molecular metal system down to very low  
temperatures, effective interstack electronic coupling is needed  
among other things to avoid Peierls transition.<sup>1</sup> The use of sulfur  
atoms on the periphery of the molecular units as a means of  
extending the  $\pi$  electron system and promoting interstack coupling  
is one of the possible strategy. We report here the results  
obtained for the  $\text{TTF}[\text{M}(\text{dmit})_2]_x$  series ( $\text{H}_2\text{dmit}$  = 4,5-dimercapto-  
1,3-dithiole-2-thione; M = Ni or Pd,  $x = 2$ ; M = Pt,  $x = 3$ ). It  
will be shown that such systems approach the objective of a "true  
3-D molecular metal" much more closely than any previous examples  
and that the nature of M plays a predominant role in determining  
the transport properties and the structure of these highly con-  
ducting transition metal complexes.

### RESULTS

Crystals of the  $\text{TTF}[\text{M}(\text{dmit})_2]_x$  complexes have been obtained



by slow interdiffusion of acetonitrile solutions of  $(\text{TTF})_3(\text{BF}_4)_2$  and  $(n\text{-Bu}_4\text{N})\text{[M(dmit)}_2\text{)]}$ . We have recently reported<sup>2</sup> that the nickel complex analogue,  $\text{TTF}[\text{Ni}(\text{dmit})_2]_2$  exhibits a metal-like conductivity temperature dependence down to 4 K, with a conductivity at room temperature of ca.  $300 \Omega^{-1} \text{cm}^{-1}$  and at 4 K of over  $10^5 \Omega^{-1} \text{cm}^{-1}$  (Figure 1). A uniform segregated stacking arrangement of the constituent TTF and  $\text{Ni}(\text{dmit})_2$  units is observed in which

close intermolecular contacts involving sulfur atoms on both types of molecules occur mainly between units in adjacent stacks, leading to a three-dimensional network of closely spaced molecules (Figure 2).

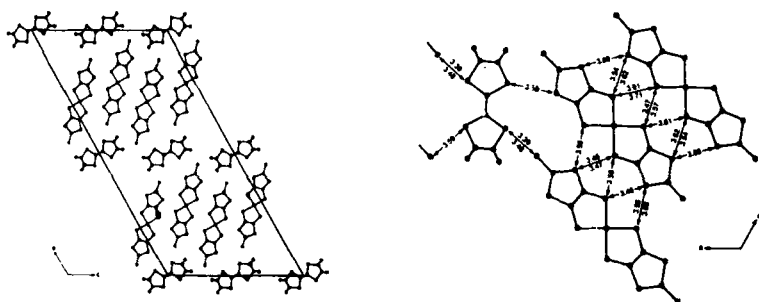
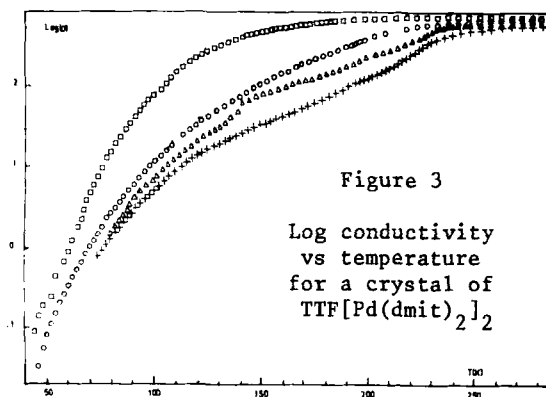


Figure 2. Crystal structure of  $\text{TTF}[\text{Ni}(\text{dmi})_2]_2$

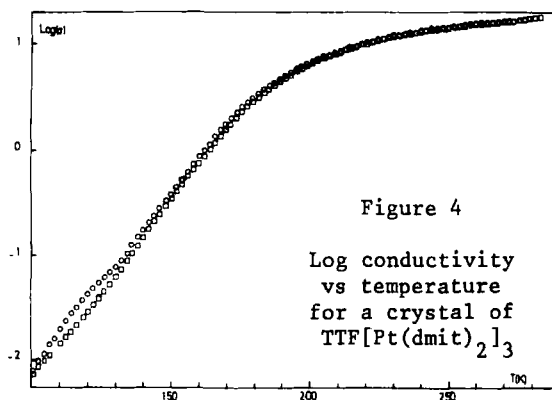
The  $\text{TTF}[\text{Pd}(\text{dmit})_2]_2$  complex analogue has the same 1:2 stoichiometry and powder diagrams indicate that this compound is isostructural to the nickel complex. The room temperature conductivity is still higher, ca.  $700 \Omega^{-1} \text{ cm}^{-1}$ .



The palladium complex exhibits a quasi-metal-like conductivity temperature dependence down to 220 K ( $\sigma_{220\text{K}} = 720 \Omega^{-1} \text{ cm}^{-1}$ ) (Figure 3). This quasi-metallic

behavior is maintained on cooling and warming cycling as long as the temperature remains higher than 220 K. Below this temperature, the crystals undergo an irreversible metal-to-insulator transition and exhibit a semi-conducting behavior on subsequent temperature cycling. However, the room temperature conductivity returns to its initial value.

The properties and structure of the platinum member of the



series are quite different: (i) the stoichiometry is now 1:3,  $\text{TTF}[\text{Pt}(\text{dmit})_2]_3$ ; (ii) these crystals exhibit a thermally activated conductivity (Figure 4;

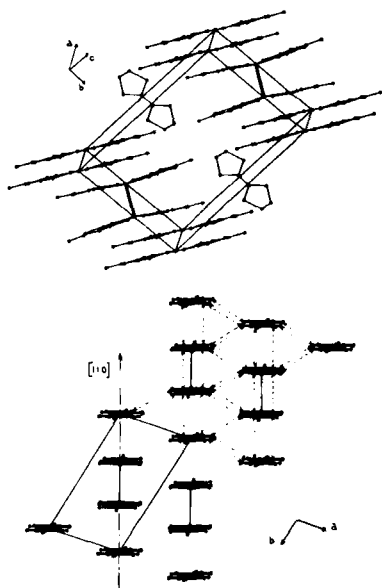


Figure 5

Crystal structure of  $\text{TTF}[\text{Pt}(\text{dmit})_2]_3$

$E_a = 0.03$  to  $0.2$  eV);  
 (iii) the semi-conducting behavior is reflected in the structure, which consists of non-uniform stacks of  $\text{Pt}(\text{dmit})_2$  units comprising alternate monomer and dimer molecules, and of uniform stacks of TTF with large stacking distances ( $6.31$  Å) (Figure 5).

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